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APPLICATION NO.	FII	LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/939,253 08/24/2001		8/24/2001	James M. Derderian	4830US (01-0106)	4830US (01-0106) 2189	
24247	7590	04/21/2006		EXAM	EXAMINER	
TRASK BRITT			WILLIAMS, ALEXANDER O			
P.O. BOX 255	50					
SALT LAKE CITY, UT 84110				ART UNIT	PAPER NUMBER	
				2826		

DATE MAILED: 04/21/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
	09/939,253	DERDERIAN, JAMES M.				
Office Action Summary	Examiner	Art Unit				
	Alexander O. Williams	2826 my				
 The MAILING DATE of this communication app Period for Reply 	ears on the cover sheet with the c	orrespondence address -				
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. If NO period for reply is specified above, the maximum statutory period versions for reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim vill apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONEI	N. nely filed the mailing date of this communication. D (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 26 Ja	nuary 2006.					
	action is non-final.					
3) Since this application is in condition for allowar		secution as to the merits is				
closed in accordance with the practice under E	•					
Disposition of Claims						
4)⊠ Claim(s) <u>1 to 13, 17-26, 31 to 33, 37 to 39 and</u>	12 to 11 islare pending in the an	olication				
4a) Of the above claim(s) 14 to 16, 27 to 39 and	· · ·					
5) Claim(s) is/are allowed.	15/41 47/4/10 47/15/41 WIL	narawii nom consideration.				
6) Claim(s) <u>1-13, 17-26, 31-33, 37-39 and 42-44 i</u>	s/are rejected					
7) Claim(s) is/are objected to.	•					
8) Claim(s) are subject to restriction and/or	election requirement					
are subject to restriction under	oleotion requirement.					
Application Papers						
9)☐ The specification is objected to by the Examine	r.					
10)☐ The drawing(s) filed on is/are: a)☐ acce	epted or b) \square objected to by the E	Examiner.				
Applicant may not request that any objection to the	drawing(s) be held in abeyance. See	37 CFR 1.85(a).				
Replacement drawing sheet(s) including the correcti	on is required if the drawing(s) is obj	ected to. See 37 CFR 1.121(d).				
11) The oath or declaration is objected to by the Ex	aminer. Note the attached Office	Action or form PTO-152.				
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the prior application from the International Bureau * See the attached detailed Office action for a list of	s have been received. s have been received in Application ity documents have been receive (PCT Rule 17.2(a)).	on No d in this National Stage				
Attachment(s) Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summary (Paper No(s)/Mail Da 5) Notice of Informal Pa 6) Other:					

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Serial Number: 09/939253 Attorney's Docket #: 4830US(01-0106)

Filing Date: 8/24/01;

Applicant: Derderian

Examiner: Alexander Williams

Applicant's Amendment filed 1/26/06 have been acknowledged. The claims being examined are claims 1 to 13, 17-26, 31 to 33, 37 to 39 and 42 to 44.

This application contains claims 14 to 16, 27 to 30, 34 to 36, 41 and 48 to 67 drawn to an invention non-elected without traverse in Paper No. 11.

Claims 40 and 68 to 102 have been canceled.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Initially, and with respect to claims 1 and 19, note that a "product by process" claim is directed to the product per se, no matter how actually made, In re Hirao, 190 USPQ 15 at 17 (footnote 3). See also In re Brown, 173 USPQ 685; In re Luck, 177 USPQ 523; In re Wertheim, 191 USPQ 90 (209 USPQ 554 does not deal with this issue); In re Fitzgerald, 205 USPQ 594, 596 (CCPA); In re Marosi et al., 218 USPQ 289 (CAFC); and most recently, In re Thorpe et al., 227 USPQ 964 (CAFC, 1985) all of which make it clear that it is the final product per se which must be determined in a "product by process" claim, and not the patentability of the process, and that, as here, an old or obvious product produced by a new method is not patentable as a product, whether claimed in "product by process" claims or not. Note that Applicant has burden of proof in such cases as the above case law makes clear.

Claims 1 to 10, 17, 19 to 26, 33, 37 to 39 and 42 to 44 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nakanishi et al. (U.S. Patent Application Publication # 2001/0013643).

For example, in claim 1, Nakanishi et al. (figures 1 to 12) specifically figure 9 show a semiconductor device for use in a stacked multi-chip assembly, comprising: a semiconductor die 2; and a dielectric spacer layer 24,25 formed on and secured to at

least a portion of a surface of said semiconductor die and protruding from the surface substantially a predetermined distance that said semiconductor die and an adjacent semiconductor die 1 of said stacked multi-chip assembly are to be spaced apart from one another, the dielectric spacer layer protruding form the surface substantially the predetermined distance, at least one intermediate conductive element 8a is secured to a bond pad of the semiconductor die, said spacer layer including voids (space between the two ends of 24,25) communicating with a lateral periphery thereof. Applicant's claim language of "the dielectric spacer layer protruding from the surface substantially the predetermined distance before at least one intermediate conductive element is secured to a bond pad of the semiconductor die" is considered product by process language in the examination of a product claim. Therefore, the Examiner is interested in finding the claimed final structure in the claim language. Whether the dielectric spacer layer is processed before or after the at least one intermediate conductive element is secured to a bond pad is does not change the final structure of the device and therefore the language has been considered is given little weigh in the examination of the claims in finding the claimed final structure..

For example, in claim 19, Nakanishi et al. (figures 1 to 12) specifically figure 9 show a semiconductor device assembly, comprising: a first semiconductor device 2; a nonconfluent spacer layer 24,25 comprising dielectric material secured to a surface of said first semiconductor device, a second semiconductor device 1 positioned over said first semiconductor device, a surface of said second semiconductor device being secured to said nonconfluent spacer layer; and the second semiconductor device, including a back side secured to the nonconfluent spacer layer. Applicant's claim language of "a nonconfluent spacer layer comprising dielectric material secured to a surface of said first semiconductor device and, prior to securing an intermediate conductive element to any of the bond pads, protruding from the active surface substantially a same distance the active surface of the first semiconductor device is to be spaced apart from the back side of a semiconductor device" is considered product by process language in the examination of a product claim. Therefore, the Examiner is interested in finding the claimed final structure in the claim language. Whether the nonconfluent spacer layer is processed before or after the securing the intermediate conductive layer element (wire) to any of the bond pads does not change the final structure of the device and therefore the language is given little weigh in the examination of the claims.

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As to the grounds of rejection under section 103, see MPEP § 2113.

In claim 37, Nakanishi et al. (figures 1 to 12) specifically figure 9 show a substrate 5 upon which one of said first semiconductor device 2 and said second semiconductor device 1 is positioned.

In claim 38, Nakanishi et al. (figures 1 to 12) specifically figure 9 show at least one bond pad of at least one of said first semiconductor device 2 and said second semiconductor device 2 is in communication with a corresponding contact area of said substrate 5.

In claim 39, Nakanishi et al. (figures 1 to 12) specifically figure 9 show the substrate comprising at least one of a circuit board, an interposer, another semiconductor device, and leads 5.

As to the grounds of rejection under section 103, see MPEP § 2113.

Claims 11 and 12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nakanishi et al. (U.S. Patent Application Publication # 2001/0013643) in view of Smith, Jr. et al. (U.S. Patent # 6,049,370).

Nakanishi et al. show the features of the claimed invention as detailed above, but fail to explicitly show a spacer layer comprising polymer, where as the polymer comprises a photoimageable polymer. Shimi does discloses that the <code>jumper</code> strips 50A, 50B, and 50C can be made of a variety of insulative materials and by a variety of techniques. For example, they can be

fabricated from a resin tape or a sheet of fiberglass impregnated with an epoxy resin using conventional circuit tape or PCB fabrication techniques. Photoimageable polymer is defined to be a photoresist polymer.

Smith, Jr. et al. is cited for showing liquid crystal light valvue using internal, fixed spacers. Specifically, Smith, Jr. et al. (figures 2 to 5) specifically figure 3 discloses a ariety of materials may be used to form the spacer pads 40, including

an oxide, such as silica or indium tin oxide, a metal, such as chromium, aluminum, or gold, and polymers, such as polyimides or photoresist materials for the purpose of giving spacing between electrical connecting materials.

Therefore, it would have been obvious to one of ordinary skill in the art to use Smith, Jr. et al.'s photoresist polymer spacer to modify Nakanishi et al.'s spacers for the purpose of giving spacing between electrical connecting materials.

Claims 18 and 31 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nakanishi et al. (U.S. Patent Application Publication # 2001/0013643) in view of Blanton (U.S. Patent # 5,220,200).

Initially, it is noted that the 35 U.S.C. § 103 rejection based on a dielectric spacer layer and a plurality of at least partially superimposed, contiguous, adhered sublayers deals with an issue (i.e., the integration of multiple pieces into one piece or conversely, using multiple pieces in replacing a single piece) that has been previously decided by the courts.

In <u>Howard v. Detroit Stove Works</u> 150 U.S. 164 (1893), the Court held, "it involves no invention to cast in one piece an article which has formerly been cast in two pieces and put together...."

In <u>In re Larson</u> 144 USPQ 347 (CCPA 1965), the term "integral" did not define over a multi-piece structure secured as a single unit. More importantly, the court went further and stated, "we are inclined to agree with the solicitor that the use of a one-piece construction instead of the [multi-piece] structure disclosed in Tuttle et al. would be merely a matter of obvious engineering choice" (bracketed material added). The court cited In re Fridolph for support.

In re Fridolph 135 USPQ 319 (CCPA 1962) deals with submitted affidavits relating to this issue. The underlying issue in In re Fridolph was related to the end result of making

a multi-piece structure into a one-piece structure. Generally, favorable patentable weight was accorded if the one-piece structure yielded results not expected from the modification of the two-piece structure into a single piece structure.

Nakanishi et al. dielectric layer can be a plurality of at least partially superimposed, contiguous, adhered sublayers.

Blanton is cited for showing provision of substrate pillars to maintain chip standoff. Specifically, Blanton (figures 1 to 3) specifically figure 3 discloses dielectric layer can be a plurality of at least partially superimposed, contiguous, adhered sublayers for the purpose of providing standoff means to space an integrated circuit.

Therefore, it would have been obvious to one of ordinary skill in the art to use the dielectric spacer layer and a plurality of at least partially superimposed, contiguous, adhered sublayers as "merely a matter of obvious engineering choice" as set forth in the above case law. However, it would have been obvious to one of ordinary skill in the art to use Blanton's series of layer to make a spacer to modify Nakanishi et al.'s spacers for the purpose of providing standoff means to space an integrated circuit.

Claims 11, 13 and 32 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nakanishi et al. (U.S. Patent Application Publication # 2001/0013643) in view of Mueller et al. (U.S. Patent # 6,316,786 B1).

Nakanishi et al. show the features of the claimed invention as detailed above, but fail to explicitly show a spacer layer comprising (all types) at least one of a glass, a silicon oxide, a silicon nitride, and a silicon oxynitride.

Mueller et al. is cited for showing an organic opto-electronic devices.

Specifically, Mueller et al. (figures 1A to 3c) specifically figure 1B discloses spacers

13 and 15 comprising silicon nitride, SiN.sub.x, SiO.sub.x,

SiO.sub.2, Siliconoxynitride (SiON), organic compounds such as polyimides, aluminiumoxide, aluminiumnitride, or titaniumoxide, for example for the purpose of providing sufficient contact between the layers and damage between the layers are avoided.

Therefore, it would have been obvious to one of ordinary skill in the art to use Mueller et al.'s spacer to modify Nakanishi's spacers for the purpose of providing sufficient contact between the layers and damage between the layers are avoided.

Response

Applicant's arguments filed 1/26/06 have been fully considered, but are not found to be persuasive in view of the outstanding modified grounds of rejections detailed above. Applicant's arguments stating "voids communicating with a lateral periphery thereof" is not found to be persuasive. In figure 9, Nakanishi et al. show an voids between 24 and 7. The spacer layers are shown as 24,25.

Accordingly, **THIS ACTION IS MADE FINAL**. See M.P.E.P. ∋ 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 C.F.R. ∋ 1.136(a).

A SHORTENED STATUTORY PERIOD FOR RESPONSE TO THIS FINAL
ACTION IS SET TO EXPIRE THREE MONTHS FROM THE DATE OF THIS ACTION.
IN THE EVENT A FIRST RESPONSE IS FILED WITHIN TWO MONTHS OF THE
MAILING DATE OF THIS FINAL ACTION AND THE ADVISORY ACTION IS NOT
MAILED UNTIL AFTER THE END OF THE THREE-MONTH SHORTENED
STATUTORY PERIOD, THEN THE SHORTENED STATUTORY PERIOD WILL
EXPIRE ON THE DATE THE ADVISORY ACTION IS MAILED, AND ANY EXTENSION

FEE PURSUANT TO 37 C.F.R. € 1.136(a) WILL BE CALCULATED FROM THE

MAILING DATE OF THE ADVISORY ACTION. IN NO EVENT WILL THE STATUTORY

PERIOD FOR RESPONSE EXPIRE LATER THAN SIX MONTHS FROM THE DATE

OF THIS FINAL ACTION.

Field of Search	Date
U.S. Class and subclass:	9/9/02
257/686,685,777,778,784-787,734,737,738,723,730,773	2/22/03
	5/8/03
	8/18/03
	11/17/03
	5/4/04
	1/23/05
	5/1/05
	10/18/05
Other Documentation:	9/9/02
foreign patents and literature in	2/22/03
257//686,685,777,778,784-787,734,737,738,723,730,773	5/8/03
	8/18/03
	11/17/03
	5/4/04
	1/23/05
	5/1/05
	10/18/05
Electronic data base(s):	9/9/02
U.S. Patents EAST	2/22/03
	5/8/03
	8/18/03
	11/17/03
	5/4/04
	1/23/05
	10/18/05

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Alexander O Williams whose telephone number is (571) 272 1924. The examiner can normally be reached on M-F 6:30-7:00PM.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan Flynn can be reached on (571) 272 1915. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

AOW 4/14/06

> Alexander Williams Primary Examiner